

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

Method of Improved High K Dielectric-Polysilicon Interface for
CMOS Devices

Application Number : 09/941827



Confirmation Number: 7551

First Named Applicant: Ronald Weimer

Attorney Docket Number: MTI-31532

Art Unit: 2813

Examiner: Yennhu B. Huynh

Search string: (6548368 or 6278166 or 6063698).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6548368	2003-04-15	Narwankar et al.	B1	438	398
	2	6278166	2001-08-21	Ogle, Jr.	B1	257	411
	3	6063698	2000-05-16	Tseng et al.		438	585

Signature

Examiner Name	Date